

AMENDMENTS

In The Specification:

On page 1, please replace the first paragraph, beginning at line 7, with the following:

--The present invention relates firstly to a read/write amplifier for a DRAM memory cell in accordance with the preamble of patent claim 1. Furthermore, the invention relates to a DRAM memory in accordance with the preamble of patent claim 10. Finally, the invention also relates to a method for evaluating DRAM memory cells of a DRAM memory.--